TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process) (darlington)

2SD1224

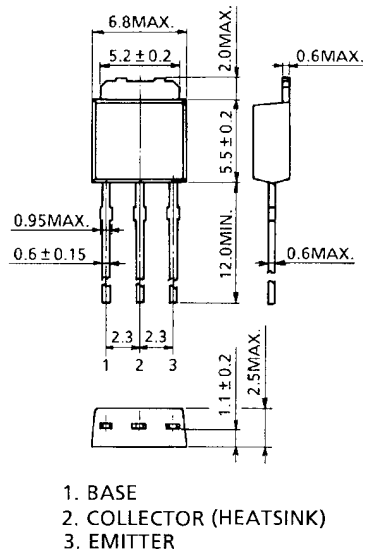
Pulse Motor Drive, Hammer Drive Applications
Switching Applications
Power Amplifier Applications

- High DC current gain: h_{FE} = 4000 (min) (V_{CE} = 2 V, I_C = 150 mA)
- Low saturation voltage: $V_{CE\ (sat)}$ = 1.5 V (max) (I_C = 1 A, I_B = 1 mA)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	30	V
Collector-emitter voltage		V_{CEO}	30	V
Emitter-base voltage		V_{EBO}	10	V
Collector current		I_C	1.5	A
Base current		I_B	0.15	A
Collector power dissipation	Ta = 25°C	P_C	1.0	W
	Tc = 25°C		10	
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	−55 to 150	°C

Unit: mm

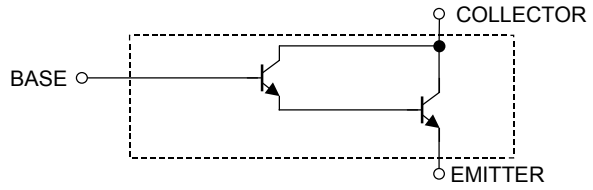


1. BASE
2. COLLECTOR (HEATSINK)
3. EMITTER

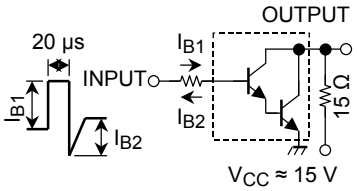
JEDEC	—
JEITA	—
TOSHIBA	2-7B1A

Weight: 0.36 g (typ.)

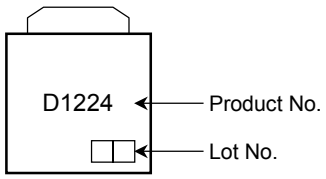
Equivalent Circuit



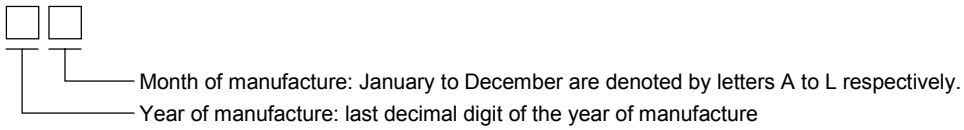
Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		I_{CBO}	V_{CB} = 30 V, I_E = 0	—	—	10	μA
Emitter cut-off current		I_{EBO}	V_{EB} = 10 V, I_C = 0	—	—	10	μA
Collector-emitter breakdown voltage		$V_{(BR)\ CEO}$	I_C = 10 mA, I_B = 0	30	—	—	V
DC current gain		h_{FE}	V_{CE} = 2 V, I_C = 150 mA	4000	—	—	
Collector-emitter saturation voltage		$V_{CE\ (sat)}$	I_C = 1 A, I_B = 1 mA	—	—	1.5	V
Base-emitter saturation voltage		$V_{BE\ (sat)}$	I_C = 1 A, I_B = 1 mA	—	—	2.2	V
Switching time	Turn-on time	t_{on}	 $I_{B1} = -I_{B2}$ = 1 mA, DUTY CYCLE ≤ 1%	—	0.18	—	μs
	Storage time	t_{stg}		—	0.6	—	
	Fall time	t_f		—	0.3	—	

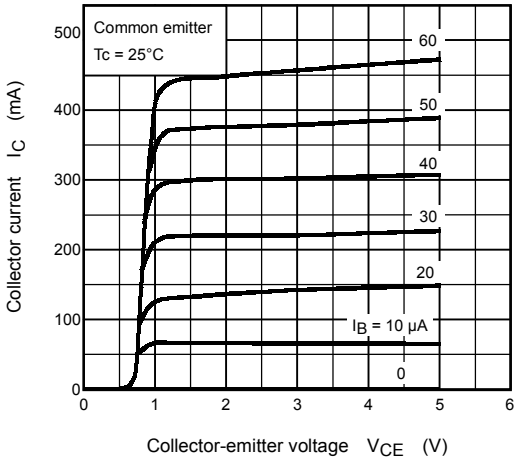
Marking



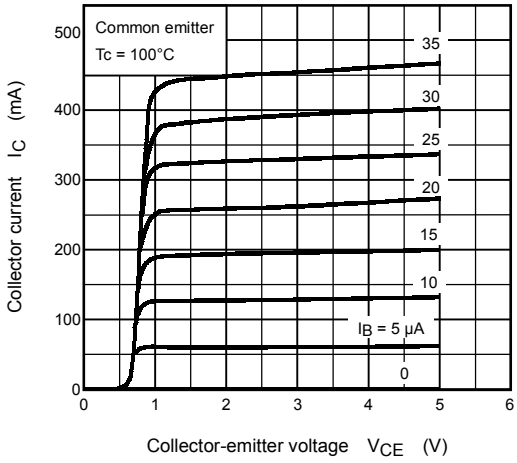
Explanation of Lot No.



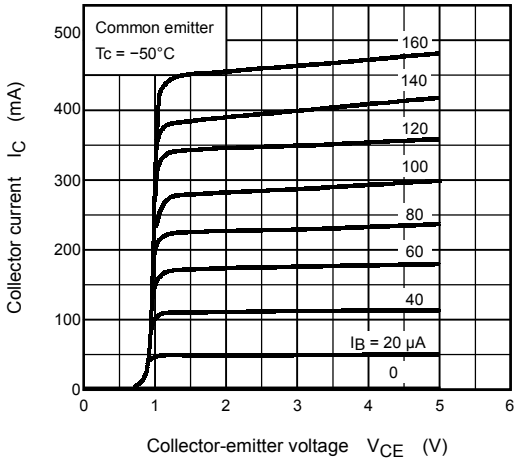
$I_C - V_{CE}$



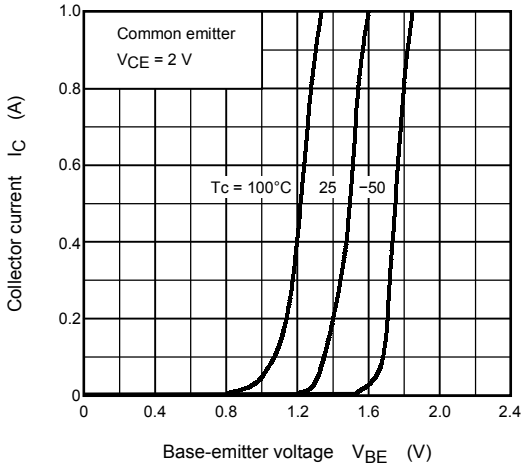
$I_C - V_{CE}$



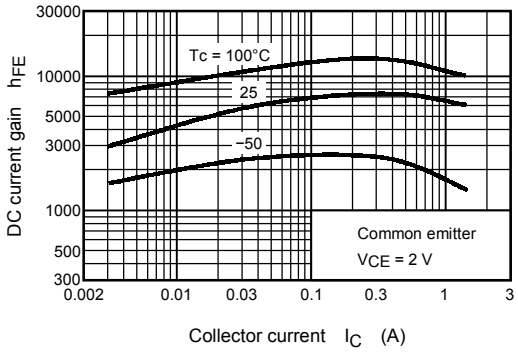
$I_C - V_{CE}$



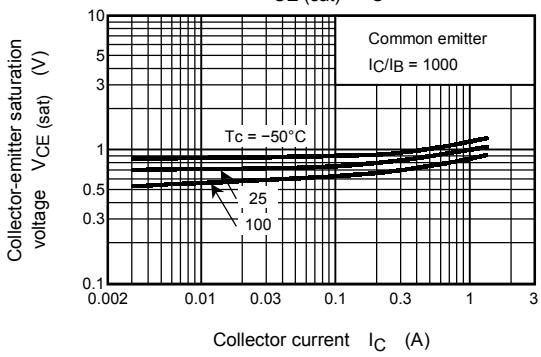
$I_C - V_{BE}$



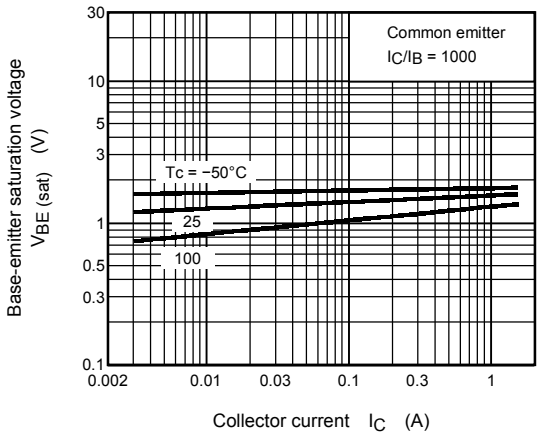
$h_{FE} - I_C$



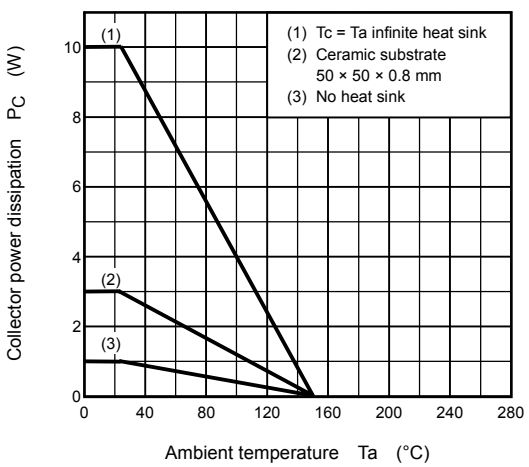
$V_{CE\ (sat)} - I_C$



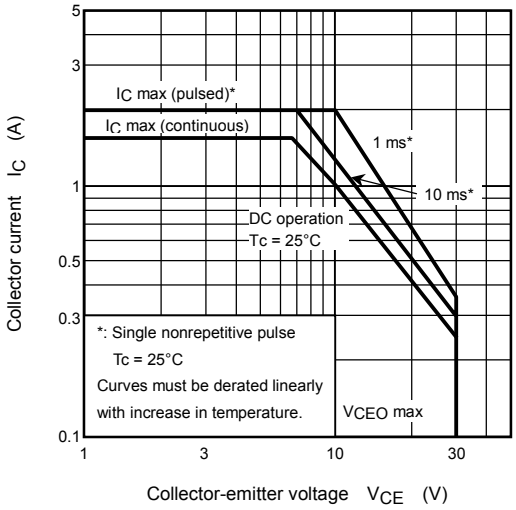
$V_{BE\ (sat)} - I_C$



$P_C - Ta$



Safe Operating Area



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